

**Comparison of the power losses in 1700V Si IGBT and SiC MOSFET modules including reverse conduction [Electronic resource]**

**Rabkowski, Jacek**; Platek, Tadeusz EPE'15 ECCE Europe : 8-10 September 2015, Geneva, Switzerland : 17th European Conference on Power Electronics and Applications 2015 / [10] p. : ill. [USB] <http://dx.doi.org/10.1109/EPE.2015.7309444>

**Floating high step-down stacked dc-dc converter based on buck-boost cells [Electronic resource]**

Tibola, Gabriel; Duarte, Jorge; **Blinov, Andrei** EPE'15 ECCE Europe : 8-10 September 2015, Geneva, Switzerland : 17th European Conference on Power Electronics and Applications 2015 / p. 1-10 : ill. [USB] <http://dx.doi.org/10.1109/EPE.2015.7309181>

**Operation of Single-Chip MOSFET and IGBT Devices after failure due to repetitive avalanche [Electronic resource]**

**Blinov, Andrei**; Norrga, Staffan; Tibola, Gabriel EPE'15 ECCE Europe : 8-10 September 2015, Geneva, Switzerland : 17th European Conference on Power Electronics and Applications 2015 / p. 1-9 : ill. [USB] <http://dx.doi.org/10.1109/EPE.2015.7309190>